



ISSUE CLASSIFICATION	
Class	Subclass

PATENT NUMBER

## U.S. UTILITY Patent Application

MA O.I.P.E. PATENT DATE  
SCANNED

APPLICATION NO.		CONT/PRIOR	CLASS	SUBCLASS	ART UNIT	EXAMINER
APPLICANTS	09/809663		257	411	2000	
			438	756	2000	10660
Mukesh Chare Christopher D'Emic Thomas Hwang Paul Janison						
TITLE	Method for improved plasma nitridation of ultra thin gate dielectrics					

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[illegible]

<input checked="" type="checkbox"/> <b>TERMINAL DISCLAIMER</b>	<b>DRAWINGS</b> Sheets Drawg.      Figs. Drawg.      Print Fig.		<b>CLAIMS ALLOWED</b> Total Claims      Print Claim for O.G.	
	<input type="checkbox"/> The term of this patent subsequent to <u>0</u> (date) has been disclosed.		<b>NOTICE OF ALLOWANCE MAILED</b> (Adjustment Examiner)      (Date)	
<input checked="" type="checkbox"/> The term of this patent shall not extend beyond the expiration date of U.S. Patent No. <u>6,444,522</u>	<input type="checkbox"/> The term of this patent shall not extend beyond the expiration date of U.S. Patent No. <u>6,444,522</u>		<b>ISSUE FEE</b> Amount Due      Date Paid	
	<input type="checkbox"/> The term of this patent shall not extend beyond the expiration date of U.S. Patent No. <u>6,444,522</u>		<b>ISSUE BATCH NUMBER</b>	
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